



GBU10005 THRU GBU1010

SILICON BRIDGE RECTIFIERS

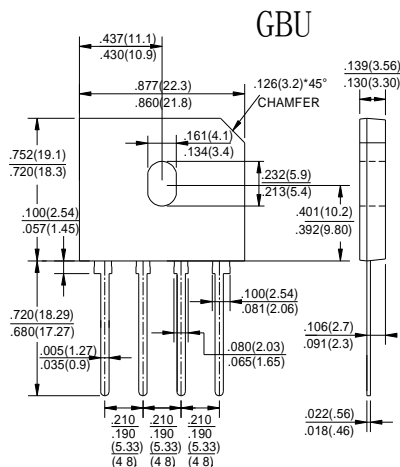
Reverse Voltage - 50 to 1000 Volts Forward Current - 10.0 Amperes

FEATURES

Ideal for printed circuit boards
 Reliable low cost construction technique
 results in inexpensive product
 High temperature soldering guaranteed:
 260°C/10 seconds/0.375" (9.5mm) lead length
 at 5 lbs.,(2.3kg) tension

MECHANICAL DATA

Case: Molded plastic
Lead: Solder plated
Polarity: As marked



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

| | SYMBOLS | GBU10005 | GBU1001 | GBU1002 | GBU1004 | GBU1006 | GBU1008 | GBU1010 | UNITS |
|---|-----------------|----------|---------|---------|---------|-------------|---------|---------|---------------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | VOLTS |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | VOLTS |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | VOLTS |
| Maximum Average Forward (with heatsink Note 2) Rectified Current @ $T_c=100^\circ\text{C}$ (without heatsink) | $I_{(AV)}$ | | | | | 10.0 3.0 | | | Amps |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | | | | | 200 | | | Amps |
| Maximum instantaneous forward voltage at 5.0A | V_F | | | | | 1.00 | | | Volts |
| Maximum instantaneous forward voltage at 10.0A | V_F | | | | | 1.10 | | | Volts |
| Maximum DC reverse current at $T_A=25^\circ\text{C}$ rated DC blocking voltage per leg $T_A=125^\circ\text{C}$ | I_R | | | | | 5.0 500 | | | μA |
| Typical Thermal Resistance (Note 2) | $R_{\theta JC}$ | | | | | 2.0 | | | $^\circ\text{C}/\text{W}$ |
| Typical Junction Capacitance Per Element (Note1) | C_J | | | | | 70 | | | pF |
| I^2t Rating for Fusing ($t<8.3\text{ms}$) | I^2t | | | | | 166 | | | A^2s |
| Operating temperature range | T_J | | | | | -55 to +150 | | | $^\circ\text{C}$ |
| storage temperature range | T_{STG} | | | | | -55 to +150 | | | $^\circ\text{C}$ |

Notes: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2. Device mounted on 100mm*100mm*1.6mm Cu plate heatsink.



RATINGS AND CHARACTERISTIC CURVES GBU10005 THRU GBU1010

Fig. 1 - Forward Current Derating Curve

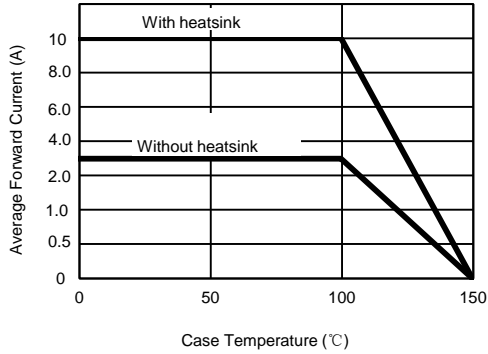


Fig. 2 - Maximum Non-Repetitive Surge Current

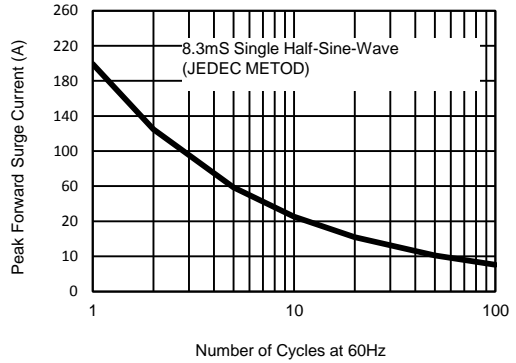


Fig. 3 - Typical Reverse Characteristics

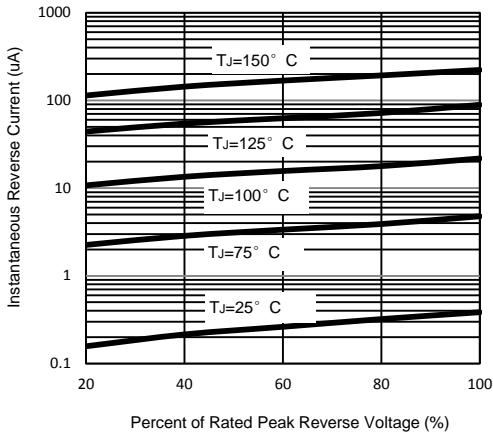


Fig. 4 - Typical Forward Characteristics

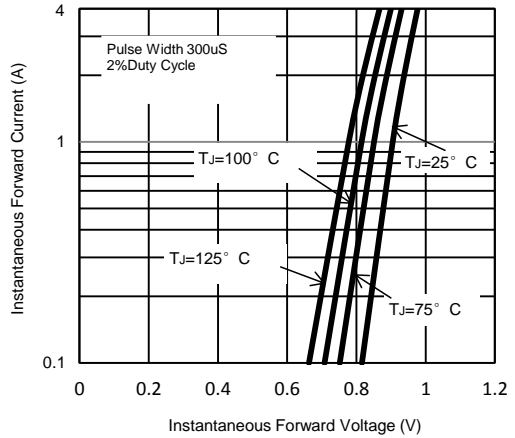


Fig. 5 - Typical Junction Capacitance

